

14701 Firestone Blvd \* La Mirada, ČA 90638 Phone: (562) 404-4474 \* Fax: (562) 404-1773 ssdi@ssdi-power.com \* www.ssdi-power.com

### **DESIGNER'S DATA SHEET** Part Number/Ordering Information <sup>1</sup> SHF11 Screening <sup>2/</sup> = Not Screened TX = TX Level TXV = TXV Level S = S Level Package Type = Axial Leaded SMS = Surface Mount Square Tab Family/Voltage 04 = 400 V 06 = 600 V 08 = 800 V09 = 900 V10 = 1000V

## SHF1104 & SHF1104SMS thru SHF1110 & SHF1110SMS

# 1 AMP 400 - 1000 V Hyper Fast Rectifier

#### Features:

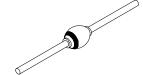
- Hyper fast recovery: 40 nsec maximum
- PIV to 1000 Volts, consult factory
- · Hermetically sealed
- · Void free construction
- For high efficiency applications
- Replaces UES 1104, UES1106, 1N6621-1N6625
- TX, TXV, and S level screening available<sup>2/</sup>

Maximum Ratings		Symbol	Value	Units
Peak Repetitive Reverse and DC Blocking \	SHF1104 SHF1106 SHF1108 SHF1109 SHF1110	V <sub>RRM</sub> V <sub>RSM</sub> V <sub>R</sub>	400 600 800 900 1000	Volts
Average Rectified Forward Current (Resistive Load, 60 Hz Sine Wave, T <sub>A</sub> = 25°C)		Io	1.0	Amps
Peak Surge Current (8.3 ms Pulse, Half Sine Wave, T <sub>A</sub> = 25°C)		I <sub>FSM</sub>	20	Amps
Operating & Storage Temperature		T <sub>OP</sub> & T <sub>STG</sub>	-65 to +175	°C
Maximum Thermal Resistance  Junction to Leads, L = 3/8  Junction to Tabs		$R_{ heta JE}$	35 28	°C/W

NOTES: Axial Lead Diode SMS

1/ For ordering information, price, and availability - contact factory.

2/ Screening based on MIL-PRF-19500. Screening flows available on request.



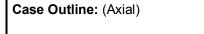


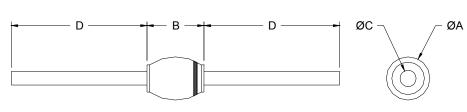


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## SHF1104 & SHF1104SMS thru SHF1110 & SHF1110SMS

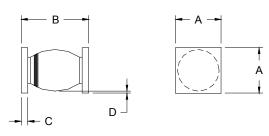
Electrical Characteristic		Symbol	Max	Units
Instantaneous Forward Voltage Drop (I <sub>F</sub> = 1A <sub>DC</sub> , T <sub>A</sub> = 25°C pulsed)	SHF1104-1106 SHF1108-1110	V <sub>F</sub>	1.35 1.65	$V_{DC}$
Instantaneous Forward Voltage Drop (I <sub>F</sub> = 1A <sub>DC</sub> , T <sub>A</sub> = -55°C pulsed)	SHF1104-1106 SHF1108-1110	V <sub>F</sub>	1.50 1.80	$V_{DC}$
Reverse Leakage Current (Rated V <sub>R</sub> , T <sub>A</sub> = 25°C pulsed)		I <sub>R</sub>	10	μΑ
Reverse Leakage Current (Rated V <sub>R</sub> , T <sub>A</sub> = 100°C pulsed)		I <sub>R</sub>	1	mA
Reverse Recovery Time (I <sub>F</sub> = 500mA, I <sub>R</sub> = 1A, I <sub>RR</sub> = 250mA, $T_A$ = 25°C)		t <sub>RR</sub>	40	nsec
Junction Capacitance $(V_R = 10V_{DC}, T_A = 25^{\circ}C, f = 1MHz)$		CJ	22	pF





DIM	MIN	MAX
Α	0.100"	0.130"
В	0.130"	0.180"
С	0.027"	0.033"
D	1.00"	

### Case Outline: (SMS)



DIM	MIN	MAX
Α	0.127"	0.140"
В	0.180"	0.230"
С	0.020"	0.030"
D	0.002"	